

TJ15S10M3

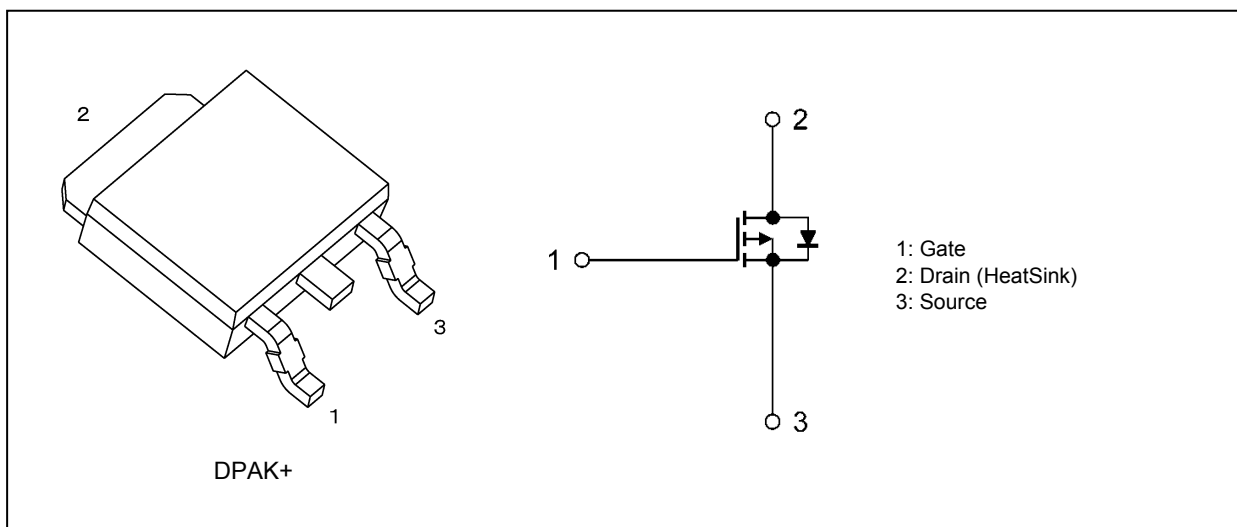
1. Applications

- Automotive
- Switching Voltage Regulators
- Motor Drivers

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 100 \text{ m}\Omega$ (typ.) ($V_{GS} = -10 \text{ V}$)
- (2) Low leakage current: $I_{DSS} = -10 \text{ }\mu\text{A}$ (max) ($V_{DS} = -100 \text{ V}$)
- (3) Enhancement mode: $V_{th} = -2.0$ to -4.0 V ($V_{DS} = -10 \text{ V}$, $I_D = -1 \text{ mA}$)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25 \text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	-100	V
Gate-source voltage	V_{GSS}	-20/+10	V
Drain current (DC) (Note 1)	I_D	-15	A
Drain current (pulsed) (Note 1)	I_{DP}	-30	A
Power dissipation ($T_c = 25^\circ\text{C}$)	P_D	75	W
Single-pulse avalanche energy (Note 2)	E_{AS}	29.3	mJ
Avalanche current	I_{AR}	-15	A
Channel temperature (Note 3)	T_{ch}	175	$^\circ\text{C}$
Storage temperature (Note 3)	T_{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production

2013-12

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	$R_{th(ch-c)}$	2.0	°C/W

Note 1: Ensure that the channel temperature does not exceed 175 °C.

Note 2: $V_{DD} = -25$ V, $T_{ch} = 25$ °C (initial), $L = 210$ μ H, $R_G = 25$ Ω , $I_{AR} = -15$ A

Note 3: The definitions of the absolute maximum channel and storage temperatures are based on AEC-Q101.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = -20/+10\text{ V}$, $V_{DS} = 0\text{ V}$	—	—	± 1	μA
Drain cut-off current	I_{DSS}	$V_{DS} = -100\text{ V}$, $V_{GS} = 0\text{ V}$	—	—	-10	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -10\text{ mA}$, $V_{GS} = 0\text{ V}$	-100	—	—	V
Drain-source breakdown voltage (Note 4)	$V_{(BR)DSX}$	$I_D = -10\text{ mA}$, $V_{GS} = 10\text{ V}$	-75	—	—	
Gate threshold voltage	V_{th}	$V_{DS} = -10\text{ V}$, $I_D = -1\text{ mA}$	-2.0	—	-4.0	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = -10\text{ V}$, $I_D = -7.5\text{ A}$	—	100	130	$\text{m}\Omega$

Note 4: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	$V_{DS} = -10\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	3200	—	pF
Reverse transfer capacitance	C_{rss}		—	135	—	
Output capacitance	C_{oss}		—	190	—	
Switching time (rise time)	t_r	See Fig. 6.2.1.	—	12	—	ns
Switching time (turn-on time)	t_{on}		—	28	—	
Switching time (fall time)	t_f		—	41	—	
Switching time (turn-off time)	t_{off}		—	290	—	

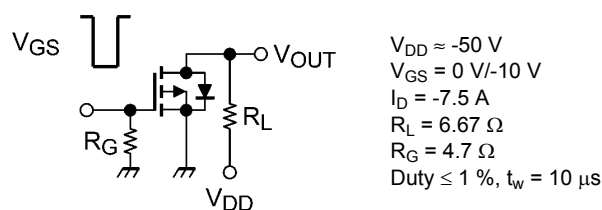


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx -80\text{ V}$, $V_{GS} = -10\text{ V}$, $I_D = -15\text{ A}$	—	69	—	nC
Gate-source charge 1	Q_{gs1}		—	9.4	—	nC
Gate-drain charge	Q_{gd}		—	20	—	nC

6.4. Source-Drain Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (DC) (Note 5)	I_{DR}	—	—	—	-15	A
Reverse drain current (pulsed) (Note 5)	I_{DRP}	—	—	—	-30	A
Diode forward voltage	V_{DSF}	$I_{DR} = -15\text{ A}$, $V_{GS} = 0\text{ V}$	—	—	1.4	V
Reverse recovery time	t_{rr}	$I_{DR} = -15\text{ A}$, $V_{GS} = 0\text{ V}$, $dI_{DR}/dt = 50\text{ A}/\mu\text{s}$	—	70	—	ns
Reverse recovery charge	Q_{rr}		—	95	—	nC

Note 5: Ensure that the channel temperature does not exceed $175\text{ }^\circ\text{C}$.

7. Marking (Note)

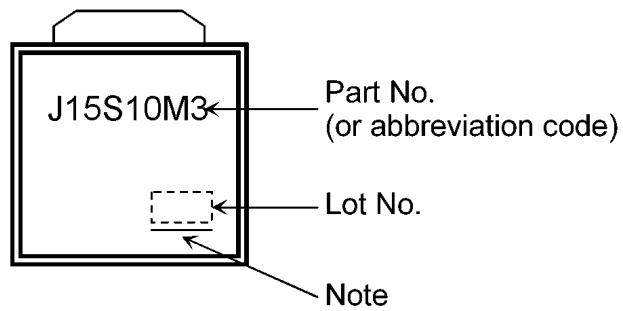


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

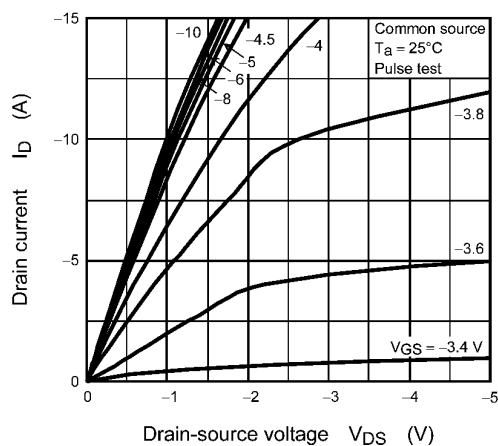


Fig. 8.1 $I_D - V_{DS}$

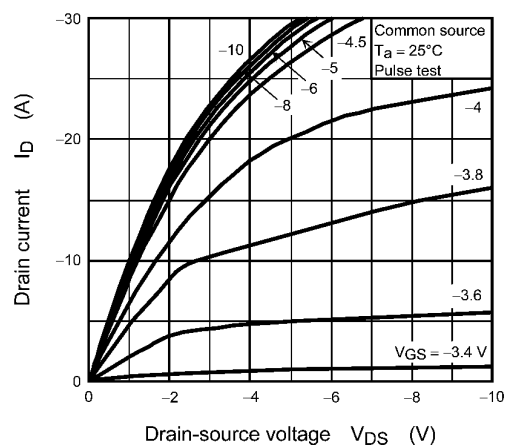


Fig. 8.2 $I_D - V_{DS}$

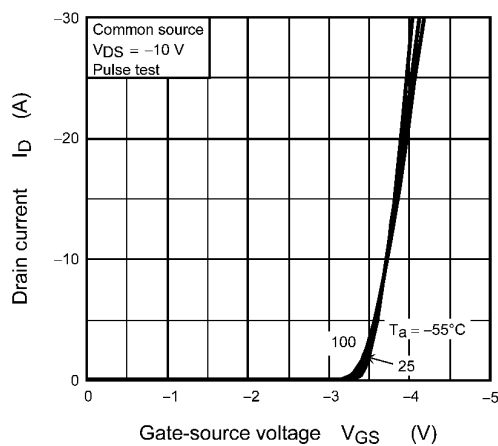


Fig. 8.3 $I_D - V_{GS}$

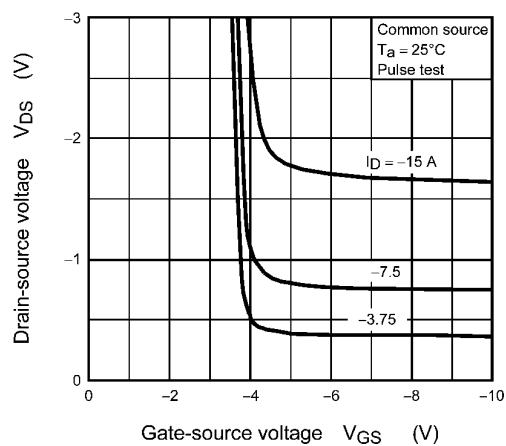


Fig. 8.4 $V_{DS} - V_{GS}$

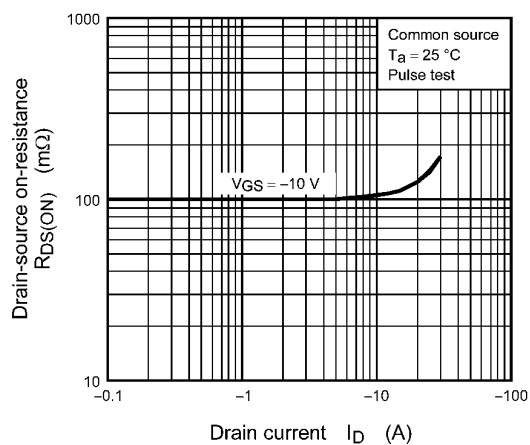


Fig. 8.5 $R_{DS(ON)} - I_D$

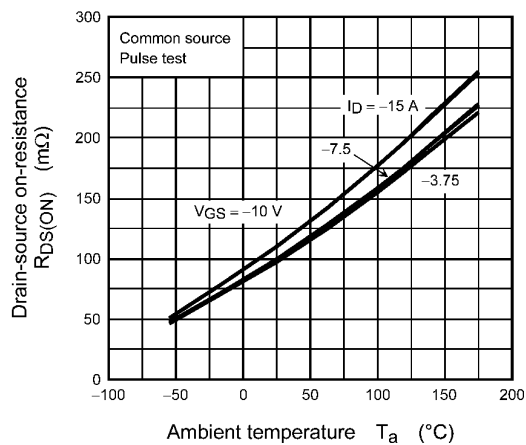


Fig. 8.6 $R_{DS(ON)} - T_a$

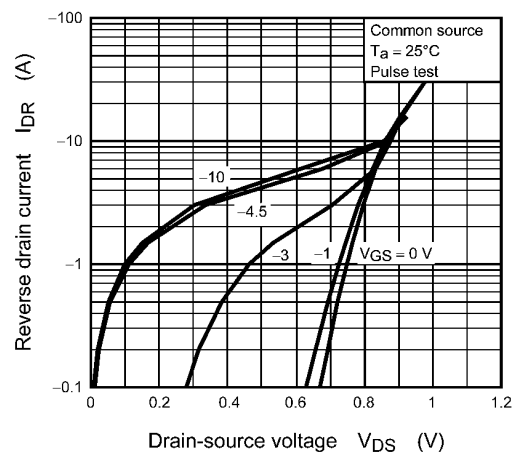


Fig. 8.7 $I_{DR} - V_{DS}$

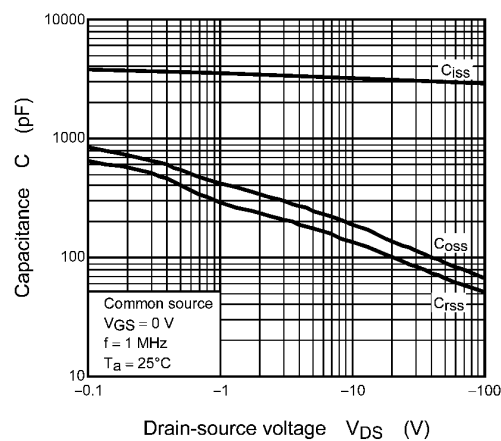


Fig. 8.8 Capacitance - V_{DS}

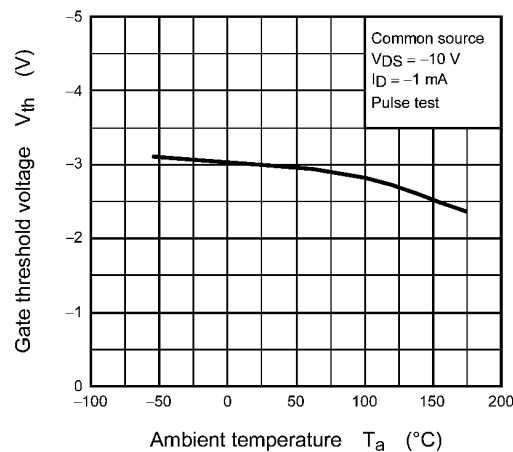


Fig. 8.9 $V_{th} - T_a$

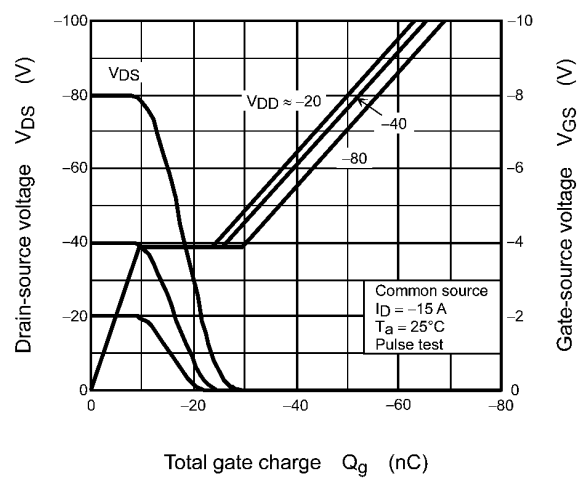


Fig. 8.10 Dynamic Input/Output Characteristics

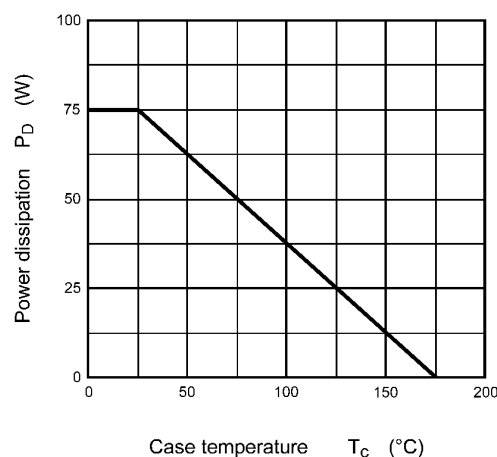


Fig. 8.11 $P_D - T_c$
(Guaranteed Maximum)

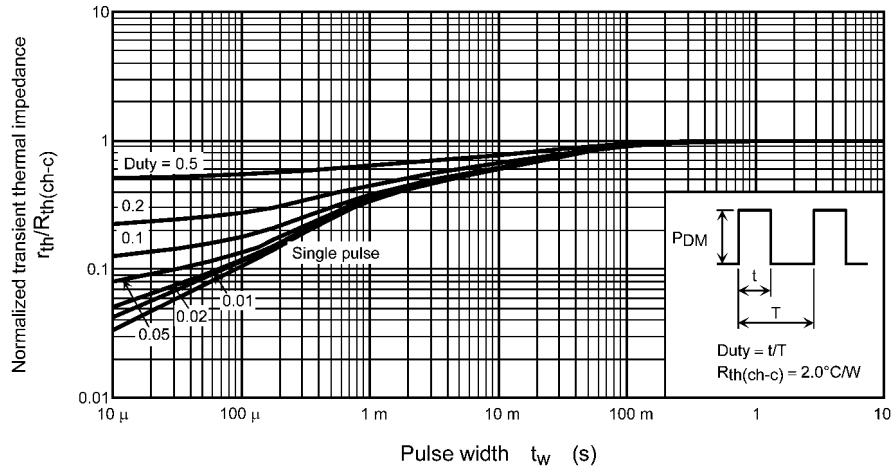


Fig. 8.12 $r_{th} - t_w$
(Guaranteed Maximum)

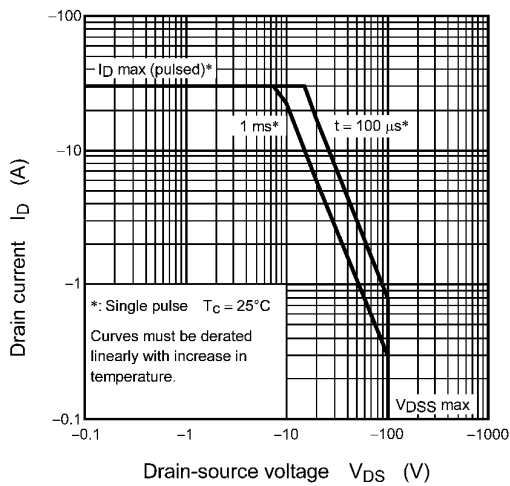


Fig. 8.13 Safe Operating Area
(Guaranteed Maximum)

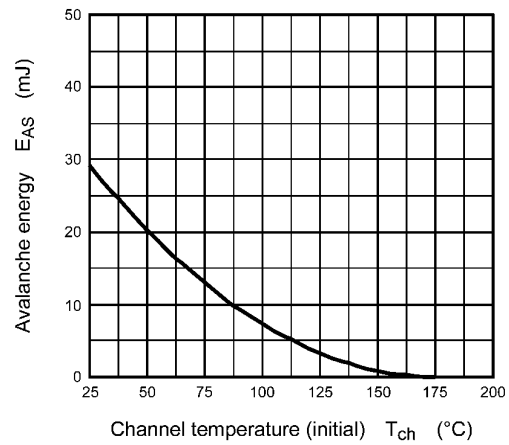
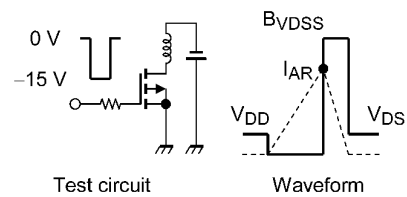


Fig. 8.14 $E_{AS} - T_{ch}$
(Guaranteed Maximum)



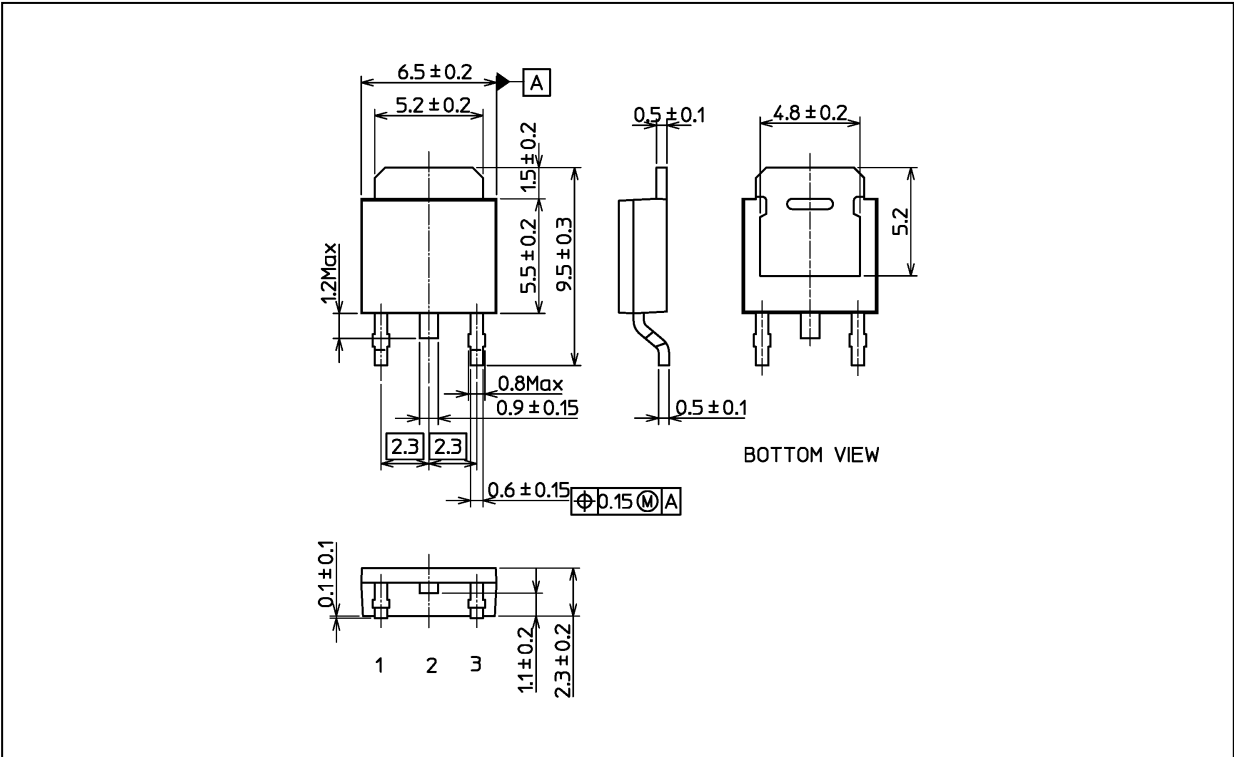
$$R_G = 25 \Omega, V_{DD} = -25 V, I_{AR} = -15 A, E_{AS} = \frac{1}{2} \cdot L \cdot I_{AR}^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

Fig. 8.15 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.36 g (typ.)

Package Name(s)
TOSHIBA: 2-7M1A
Nickname: DPAK+

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